

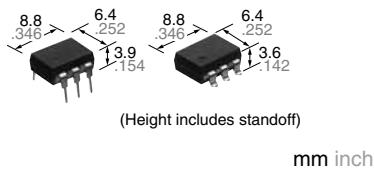


**Normally closed 6-pin type  
of 400V load voltage**

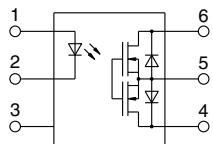
**PhotoMOS®**

**GU 1 Form B  
(AQV414)**

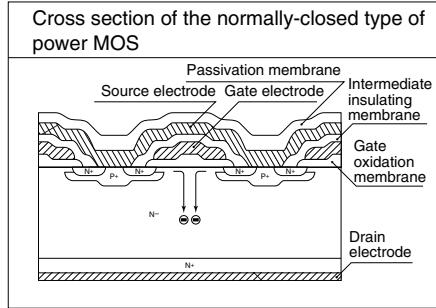
### FEATURES



mm inch



**RoHS compliant**



**1. Low on-resistance (Typ. 26Ω) for normally-closed type**

This has been achieved thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.

**2. Controls low-level analog signals**  
 PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

**3. High sensitivity and low on-resistance**

Can control max. 0.15 A load current with 5 mA input current.

**4. Low-level off state leakage current of max. 1 μA**

### TYPICAL APPLICATIONS

- Security equipment
- Telephone equipment (Dial pulse)
- Measuring instruments

### TYPES

	Output rating*		Package	Part No.				Packing quantity				
	Load voltage	Load current		Through hole terminal	Surface-mount terminal							
					Tube packing style		Tape and reel packing style					
AC/DC dual use	400 V	120 mA	DIP6-pin	AQV414	AQV414A	AQV414AX	AQV414AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.			

\*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

### RATING

**1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)**

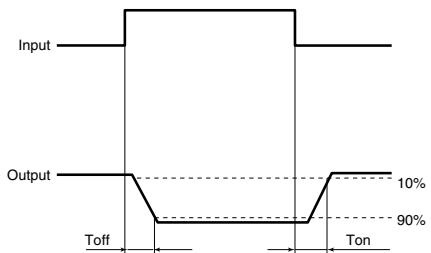
Item		Symbol	Type of connection	AQV414(A)		Remarks
Input	LED forward current	I <sub>F</sub>	A	50 mA		
	LED reverse voltage	V <sub>R</sub>		5 V		
	Peak forward current	I <sub>FP</sub>		1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	P <sub>in</sub>		75 mW		
Output	Load voltage (peak AC)	V <sub>L</sub>	B	400 V		
	Continuous load current	I <sub>L</sub>		0.12 A	A connection: Peak AC, DC B, C connection: DC	
	Peak load current	I <sub>peak</sub>		0.13 A		
	Power dissipation	P <sub>out</sub>		0.15 A		
Total power dissipation		P <sub>T</sub>		0.3 A	A connection: 100 ms (1 shot), V <sub>L</sub> = DC	
I/O isolation voltage		V <sub>Iso</sub>		500 mW		
Ambient temperature	Operating	T <sub>opr</sub>		550 mW		
	Storage	T <sub>stg</sub>		1,500 Vrms		
				-40 to +85°C	-40 to +185°F	(Non-icing at low temperatures)
				-40 to +100°C	-40 to +212°F	

# GU 1 Form B (AQV414)

## 2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV414(A)	Condition
Input	LED operate (OFF) current	Typical Maximum	$I_{Foff}$	— 1.0 mA 3.0 mA	$I_L = \text{Max.}$
	LED reverse (ON) current	Minimum	$I_{For}$	— 0.4 mA	$I_L = \text{Max.}$
		Typical		0.95 mA	
	LED dropout voltage	Typical Maximum	$V_F$	— 1.25 V (1.14 V at $I_F = 5 \text{ mA}$ ) 1.5 V	$I_F = 50 \text{ mA}$
Output	On resistance	Typical Maximum	$R_{on}$	A 26 Ω 50 Ω	$I_F = 0 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s
		Typical Maximum	$R_{on}$	B 20 Ω 25 Ω	$I_F = 0 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s
		Typical Maximum	$R_{on}$	C 10 Ω 12.5 Ω	$I_F = 0 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s
	Off state leakage current	Maximum	$I_{\text{Leak}}$	— 1 μA	$I_F = 5 \text{ mA}$ $V_L = \text{Max.}$
	Operate (OFF) time*	Typical Maximum	$T_{off}$	— 0.47 ms 1.0 ms	$I_F = 0 \text{ mA} \rightarrow 5 \text{ mA}$ $I_L = \text{Max.}$
	Reverse (ON) time*	Typical Maximum	$T_{on}$	— 0.28 ms 1.0 ms	$I_F = 5 \text{ mA} \rightarrow 0 \text{ mA}$ $I_L = \text{Max.}$
	I/O capacitance	Typical Maximum	$C_{iso}$	— 0.8 pF 1.5 pF	$f = 1 \text{ MHz}$ $V_B = 0 \text{ V}$
	Initial I/O isolation resistance	Minimum	$R_{iso}$	— 1,000 MΩ	500 V DC

\*Operate/Reverse time



## 3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

Item	Symbol	Min.	Max.	Unit
LED current	$I_F$	5	30	mA
AQV414(A)	$V_L$	—	320	V
Load voltage (Peak AC)	$I_L$	—	0.12	A
Continuous load current (A connection)				

■ These products are not designed for automotive use.

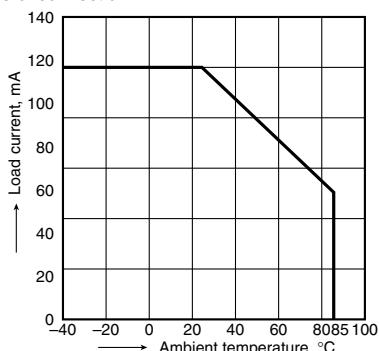
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

## REFERENCE DATA

### 1. Load current vs. ambient temperature characteristics

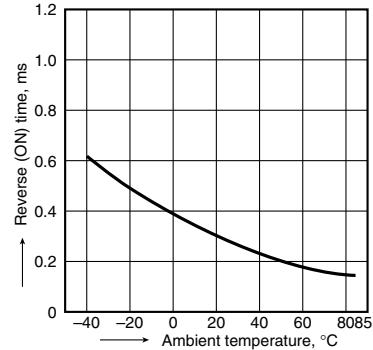
Allowable ambient temperature: -40 to +85°C  
-40 to +185°F

Type of connection: A



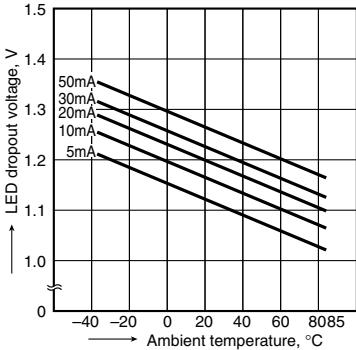
### 4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



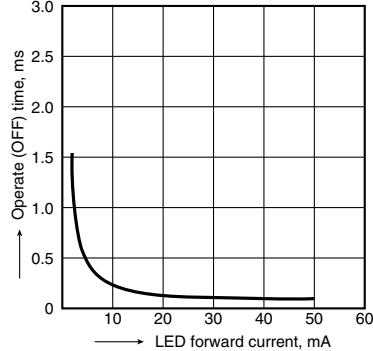
### 7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



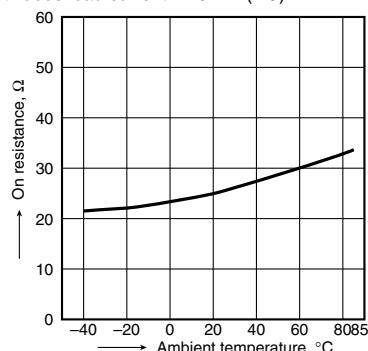
### 10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;  
Load voltage: 400 V (DC); Continuous load current:  
120 mA (DC); Ambient temperature: 25°C 77°F



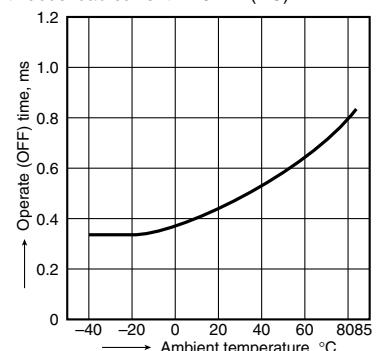
### 2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;  
LED current: 0 mA;  
Continuous load current: 120 mA (DC)



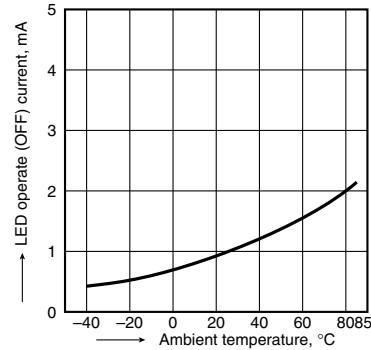
### 3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5mA;  
Load voltage: 400 V (DC);  
Continuous load current: 120 mA (DC)



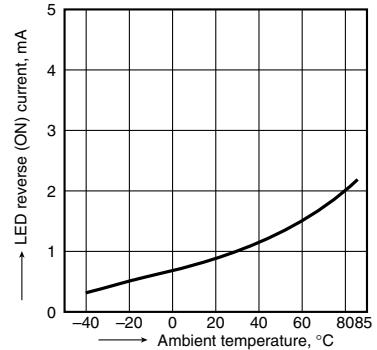
### 5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: 400 V (DC);  
Continuous load current: 120 mA (DC)



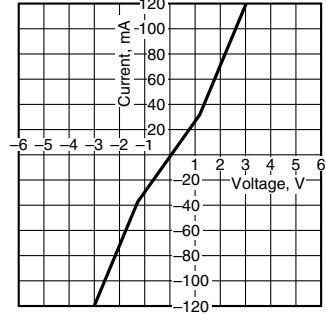
### 6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: 400 V (DC);  
Continuous load current: 120 mA (DC)



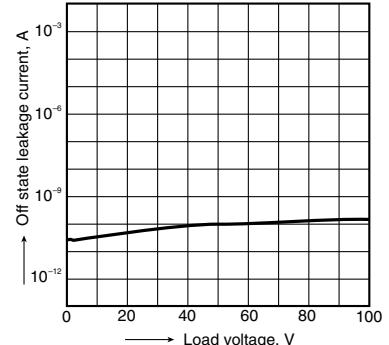
### 8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;  
Ambient temperature: 25°C 77°F



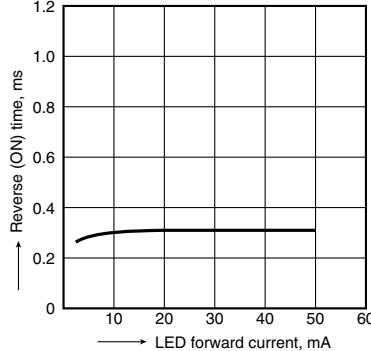
### 9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;  
LED current: 5 mA; Ambient temperature: 25°C 77°F



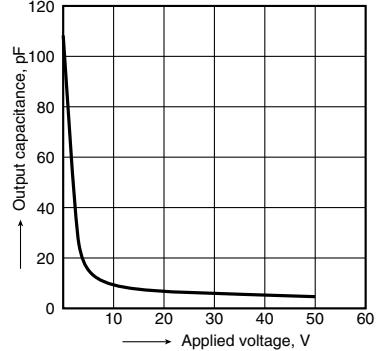
### 11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;  
Load voltage: 400 V (DC); Continuous load current:  
120 mA (DC); Ambient temperature: 25°C 77°F



### 12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;  
LED current: 5 mA; Frequency: 1 MHz;  
Ambient temperature: 25°C 77°F



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\*Recognized in Japan, the United States, all member states of European Union and other countries.

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Please contact .....

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